

**--RELATED PATENT DATA**

This patent resulted from a continuation application of U.S. Patent Application Serial No. 09/138,150, filed August 21, 2000, entitled "Field Effect Transistors, Integrated Circuitry, Methods of Forming Field Effect Transistor Gates, and Methods of Forming Integrated Circuitry", naming Charles H. Dennison as inventor, the disclosure of which is incorporated by reference.--

"FIELD" SEE 02/00